

OPA651

Wideband, Low Power Voltage Feedback OPERATIONAL AMPLIFIER

FEATURES

- STABLE IN GAINS: $\geq 2V/V$
- LOW POWER: 50mW
- BANDWIDTH: 470MHz at $G = 2$
- FAST SETTLING TIME: 16ns to 0.01%
- LOW HARMONICS: -78dB at 5MHz
- LOW INPUT BIAS CURRENT: $4\mu A$
- DIFFERENTIAL GAIN/PHASE ERROR: 0.01%/0.025°
- LOW VOLTAGE NOISE: $4.6nV/\sqrt{Hz}$

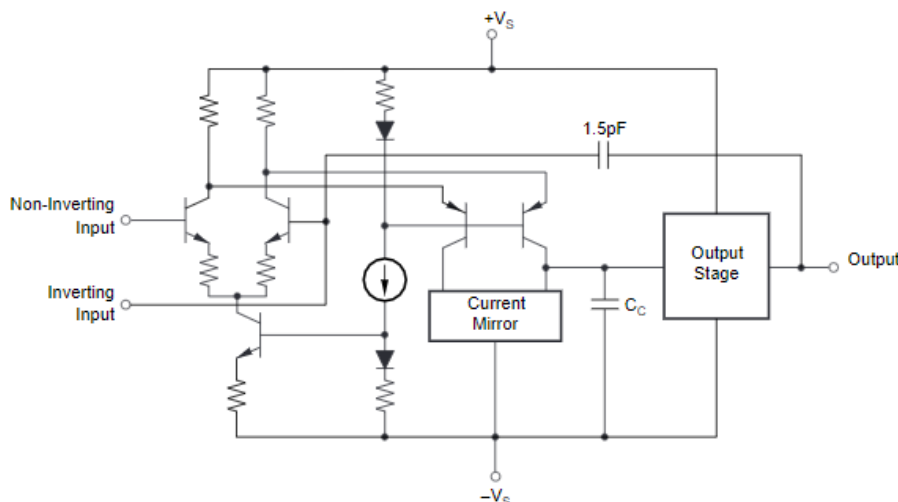
APPLICATIONS

- HIGH RESOLUTION VIDEO
- MONITOR PREAMPLIFIER
- CCD IMAGING AMPLIFIER
- ULTRASOUND SIGNAL PROCESSING
- ADC/DAC GAIN AMPLIFIER
- BASEBAND SIGNAL PROCESSING

DESCRIPTION

The OPA651 is a low power, wideband voltage feedback operational amplifier. It features a bandwidth at $G = +2$ of 470MHz as well as a 12-bit settling time of only 16ns. The wide bandwidth and true differential input stage make it suitable for use in a variety of applications. Its low distortion gives exceptional performance for telecommunications, medical imaging and video applications.

The OPA651 is compensated for stability in gains of two or more, differentiating it from the unity gain stable OPA650. Its unusual combination of speed, accuracy and low power make it an outstanding choice for many portable, multi-channel and other high speed applications, where power is at a premium.



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SPECIFICATIONS

At $T_A = +25^\circ\text{C}$, $V_S = \pm 5\text{V}$, $R_L = 100\Omega$, $R_{FB} = 402\Omega$, $G = +2$, unless otherwise noted.

PARAMETER	CONDITIONS	OPA651U, N			OPA651UB, NB			UNITS
		MIN	TYP	MAX	MIN	TYP	MAX	
FREQUENCY RESPONSE Closed-Loop Bandwidth ⁽²⁾ Gain Bandwidth Product Slew Rate Over Specified Temperature Rise Time Fall Time Settling Time 0.01% 0.1% 1% Spurious Free Dynamic Range Differential Gain Differential Phase Bandwidth For 0.1dB Flatness	$G = +2$		470			*(1)		MHz
	$G = +5$		70			*		MHz
	$G = +10$		34			*		MHz
			340			*		MHz
		$G = +2, V_O = 2\text{V}$ step		300			*	V/ μs
				275			*	V/ μs
		0.2V Step		0.8			*	ns
		0.2V Step		0.8			*	ns
		$G = +2, V_O = 2\text{V}$ step		16.2			*	ns
		$G = +2, V_O = 2\text{V}$ step		11.5			*	ns
		$G = +2, V_O = 2\text{V}$ step		7.2			*	ns
	$G = +2, f = 5.0\text{ MHz}, V_O = 2\text{Vp-p},$ $R_L = 100\Omega$		67			*	dBc	
	$R_L = 400\Omega$		78			*	dBc	
	$G = +2, \text{NTSC}, V_O = 1.4\text{Vp}, R_L = 150\Omega$		0.01			*	%	
	$G = +2, \text{NTSC}, V_O = 1.4\text{Vp}, R_L = 150\Omega$		0.025			*	Degrees	
	$G = +2$		43			*	MHz	
INPUT OFFSET VOLTAGE Input Offset Voltage Average Drift Power Supply Rejection ($+V_S$) ($-V_S$)			± 1 ± 3	± 5.0		*	± 2.0	mV $\mu\text{V}/^\circ\text{C}$
	$V_S = \pm 4.5\text{V}$ to $\pm 5.5\text{V}$	65	85		70	*		dB
		52	60		55	*		dB
INPUT BIAS CURRENT Input Bias Current Over Temperature Input Offset Current Over Temperature	$V_{CM} = 0\text{V}$		4 6	20 30		*	10 20	μA μA
	$V_{CM} = 0\text{V}$		0.4	1.5		*	*	μA
			0.9	3.0		*	*	μA
								μA
INPUT NOISE Input Voltage Noise Noise Density, $f = 100\text{Hz}$ $f = 10\text{kHz}$ $f = 1\text{MHz}$ Voltage Noise, BW = 10Hz to 100MHz Input Bias Current Noise Current Noise Density, $f = 0.1\text{Hz}$ to 20kHz Noise Figure (NF)			13 4.6 4.6			*		$\text{nV}/\sqrt{\text{Hz}}$ $\text{nV}/\sqrt{\text{Hz}}$ $\text{nV}/\sqrt{\text{Hz}}$
			46			*		μVrms
			1.1				*	$\text{pA}/\sqrt{\text{Hz}}$
		$R_S = 10\text{k}\Omega$	3.2				*	dB
		$R_S = 50\Omega$	14				*	dB
INPUT VOLTAGE RANGE Common-Mode Input Range Over Specified Temperature Common-Mode Rejection			± 3.0	± 3.5		*		V
			75	90		80	*	V
	$V_{CM} = \pm 0.5\text{V}$							dB
INPUT IMPEDANCE Differential Common-Mode			60 1			*		k Ω pF
			2.6 1			*		M Ω pF
OPEN-LOOP GAIN Open-Loop Voltage Gain Over Specified Temperature	$V_O = \pm 2\text{V}, R_L = 100\Omega$	42	50		45	*		dB
	$V_O = \pm 2\text{V}, R_L = 100\Omega$	40			42			dB
OUTPUT Voltage Output Over Specified Temperature Current Output, Sourcing Over Specified Temperature Current Output, Sinking Over Specified Temperature Short Circuit Current Output Resistance	No Load	± 2.2	± 3.0		± 2.4	*		V
	$R_L = 250\Omega$	± 2.2	± 2.5		± 2.4	*		V
	$R_L = 100\Omega$	± 2.0	± 2.3		± 2.1	*		V
		75	110		*	*		mA
		65			*	*		mA
		65	85		*	*		mA
		35			*	*		mA
			150			*		mA
	0.1MHz, $G = +2$		0.05			*		Ω
POWER SUPPLY Specified Operating Voltage Operating Voltage Range Quiescent Current Over Specified Temperature			± 5	± 5.5	*	*	*	V
		± 4.5	± 5.1	± 5.5		*	± 6.5	V
				± 7.75		*	± 7.5	mA
				± 8.75		*		mA
TEMPERATURE RANGE Specification: U, N, UB, NB Thermal Resistance, θ_{JA} U SO-8 N SOT23-5		-40		+85	*	*		$^\circ\text{C}$
			125			*		$^\circ\text{C/W}$
			150			*		$^\circ\text{C/W}$

NOTES: (1) An asterisk (*) specifies the same value as the grade to the left. (2) Frequency response can be strongly influenced by PC board parasitics. The OPA651 is nominally compensated assuming 2pF parasitic load. The demonstration boards show low parasitic layouts for the different package styles.